

SILICON NPN TRIPLE DIFFUSED MESA TYPE
(DARLINGTON POWER)

2SD648A

HIGH POWER SWITCHING APPLICATIONS.
DC MOTOR CONTROL APPLICATIONS.
ELECTRIC CAR APPLICATIONS.

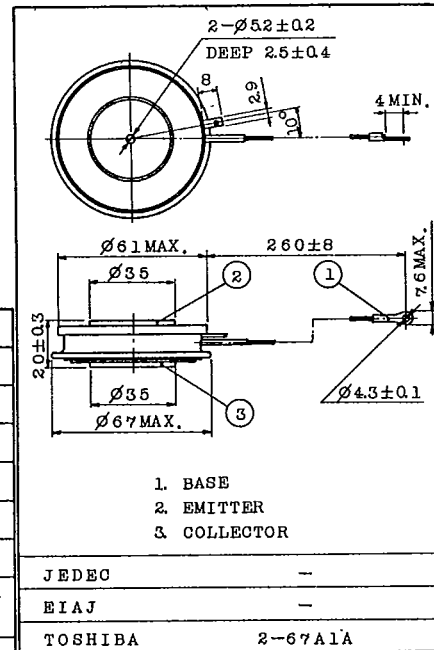
FEATURES:

- . High Voltage : $V_{CEO(SUS)}=300V$
- . Triple Diffused Design.
- . Darlington Design.

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	300	V
Collector-Emitter Voltage	$V_{CEO(SUS)}$	300	V
Emitter-Base Voltage	V_{EBO}	4	V
Collector Current	I_C	400	A
Emitter Current	I_E	-400	A
Base Current	I_B	12	A
Thermal Resistance (Double Side Cooling)	$R_{th(j-c)}$	0.04	°C/W
Junction Temperature	T_j	125	°C
Storage Temperature Range	T_{stg}	-40 ~ 150	°C
Mounting Force Required	F	1000±100	kg

INDUSTRIAL APPLICATIONS
Unit in mm



JEDEC	-
EIAJ	-
TOSHIBA	2-67A1A

Weight : 250g

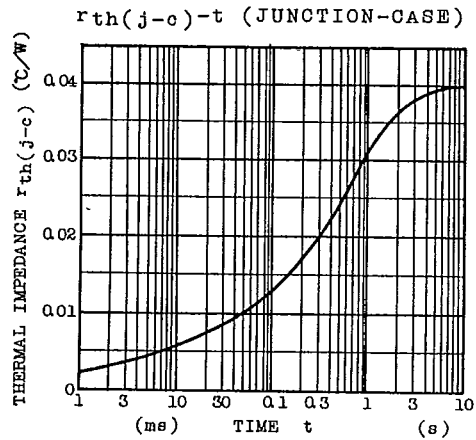
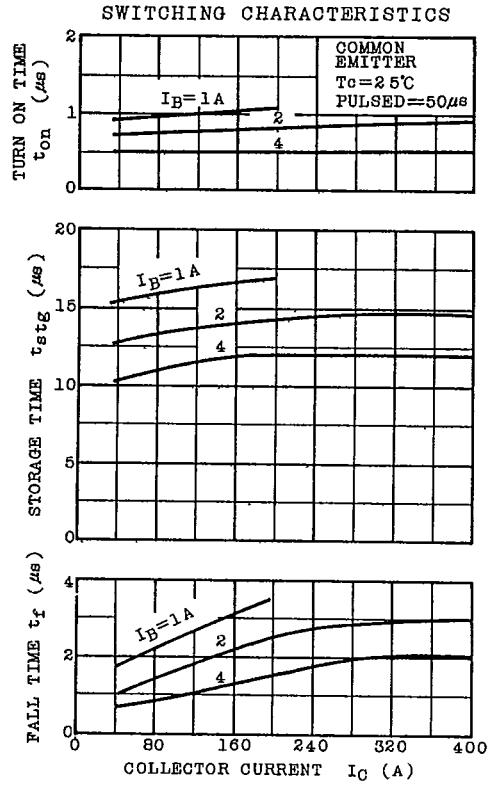
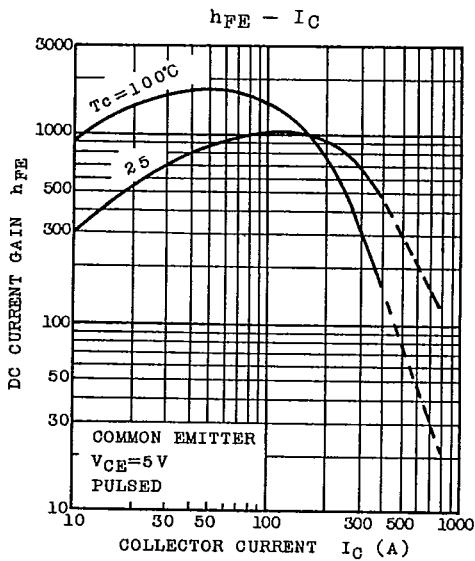
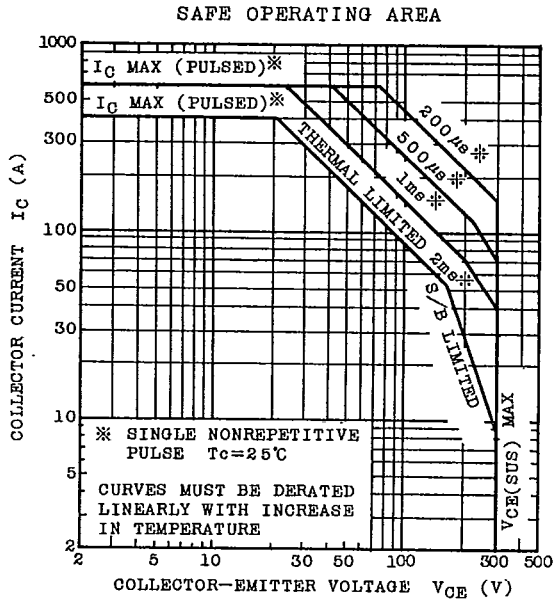
ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=400A$	100	400	-	
Collector-Emitter Sustaining Voltage	$V_{CEO(SUS)}$	$I_C=0.5A, L=40mH$	300	-	-	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=400A, I_B=8A$ (Note)	-	-	2.0	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=400A, I_B=8A$ (Note)	-	-	2.5	V
Collector Cut-off Current	I_{CEO}	$V_{CE}=300V, I_B=0$	-	1.0	10	mA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=4V, I_C=0$	-	50	250	mA
Switching Time	Turn-on Time	$I_C=400A, I_{B1}=4A, I_{B2}=4A, V_C=100V$	-	1.0	3.0	μs
	Storage Time		-	8	13	μs
	Fall Time		-	2	3.0	μs

Note: Pulse Test, Pulse Width ≤ 300μs, Duty Cycle ≤ 3%
Mounting Force; F=1000kg

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